#### Res. Asst. PhD OZAN ÖZTÜRK

#### **Personal Information**

Email: ozanozturk@cumhuriyet.edu.tr

Web: https://avesis.cumhuriyet.edu.tr/ozanozturk

International Researcher IDs

ORCID: 0000-0002-9592-3152 ScopusID: 57199406022 Yoksis Researcher ID: 255311



#### **Education Information**

Doctorate, Ataturk University, Fen Bilimleri Enstitüsü, Nanoscience and Nanoengineering, Turkey 2019 - 2024

Associate Degree, Sivas Cumhuriyet University, Sağlık Hizmetleri Meslek Yüksekokulu,

Optician Pr., Turkey 2022 - 2023

Associate Degree, Anadolu University, Açıköğretim Fakültesi, Computer Programming Pr.,

Turkey 2021 - 2023

Postgraduate, Sivas Cumhuriyet University, Fen Bilimleri Enstitüsü, Nanotechnology

Engineering, Turkey 2016 - 2018

Undergraduate Double Major, Sivas Cumhuriyet University, Mühendislik Fakültesi,

Mechanical Engineering, Turkey 2012 - 2016

Undergraduate, Sivas Cumhuriyet University, Mühendislik Fakültesi, Electrical-Electronics

Engineering, Turkey 2011 - 2015

# Foreign Languages

English, B2 Upper Intermediate

### **Dissertations**

Doctorate, Development of Hybrid Nickel Sulfide-Based Supercapacitor Device, Ataturk University, Fen Bilimleri Enstitüsü, Nanoscience and Nanoengineering, 2024

Postgraduate, Electronic Properties of Triple GaAlAs/GaAs and GaInAs/GaAs Nano Structures, Sivas Cumhuriyet University, Fen Bilimleri Enstitüsü, Nanotechnology Engineering, 2018

#### Research Areas

Electrical and Electronics Engineering, Mechanical Engineering, Engineering and Technology

# **Academic Titles / Tasks**

Research Assistant PhD, Sivas Cumhuriyet University, Mühendislik Fakültesi, Nanoteknoloji Mühendisliği, 2024 -

#### Published journal articles indexed by SCI, SSCI, and AHCI

I. Layered Transition Metal Sulfides for Supercapacitor Applications

ÖZTÜRK O., GÜR E.

ChemElectroChem, 2024 (SCI-Expanded)

II. High harmonic generations triggered by the intense laser field in GaAs/AlxGa1-xAs honeycomb quantum well wires

Alaydin B. Ö., Altun D., Öztürk O., Öztürk E.

Materials Today Physics, vol.38, 2023 (SCI-Expanded)

III. High harmonic generations in GaAs/AlGaAs superlattice: Effect of electric and magnetic field Öztürk E., Altun D., Öztürk O., Alaydin B. Ö.

Solid State Communications, vol.372, 2023 (SCI-Expanded)

IV. Linear and nonlinear optical properties of a superlattice with periodically increased well width under electric and magnetic fields

ALTUN D. D., ÖZTÜRK O., ALAYDİN B. Ö., ÖZTÜRK E.

MICRO AND NANOSTRUCTURES, vol.166, 2022 (SCI-Expanded)

V. Intense laser field effect on the nonlinear optical properties of triple quantum wells consisting of parabolic and inverse-parabolic quantum wells

Öztürk O., Alaydin B. Ö., Altun D., Öztürk E.

Laser Physics, vol.32, no.3, 2022 (SCI-Expanded)

VI. Depending on the intense laser field of the nonlinear optical rectification, second and third harmonic generation in asymmetric parabolic-step and inverse parabolic-step quantum wells ÖZTÜRK O., ÖZTÜRK E., Elagoz S.

PHYSICA SCRIPTA, vol.94, no.11, 2019 (SCI-Expanded)

VII. The effect of intense laser field on the nonlinear optical features in asymmetric multiple step and inverse V-shaped multiple step quantum wells

Öztürk O., Öztürk E., Elagoz S.

LASER PHYSICS, vol.29, 2019 (SCI-Expanded)

VIII. Dependence on well widths of total optical absorption coefficient of asymmetric triple GaAlAs/GaAs and GaInAs/GaAs quantum wells

ÖZTÜRK O., ÖZTÜRK E., Elagoz S.

INTERNATIONAL JOURNAL OF MODERN PHYSICS B, vol.33, no.17, 2019 (SCI-Expanded)

IX. Nonlinear Optical Rectification, Second and Third Harmonic Generations in Square-Step and Graded-Step Quantum Wells under Intense Laser Field

Ozturk O., Ozturk E., Elagoz S.

CHINESE PHYSICS LETTERS, vol.36, no.6, 2019 (SCI-Expanded)

X. Linear and nonlinear optical properties of asymmetric triple quantum wells under intense laser field Ozturk O., Ozturk E., Elagoz S.

LASER PHYSICS, vol.29, no.5, 2019 (SCI-Expanded)

XI. Linear and nonlinear optical absorption coefficient and electronic features of triple GaAlAs/GaAs and GaInAs/GaAs quantum wells depending on barrier widths

Ozturk O., Ozturk E., Elagoz S.

OPTIK, vol.180, pp.394-405, 2019 (SCI-Expanded)

XII. The effect of barrier width on the electronic properties of double GaAlAs/GaAs and GaInAs/GaAs quantum wells

Ozturk O., Ozturk E., Elagoz S.

JOURNAL OF MOLECULAR STRUCTURE, vol.1156, pp.726-732, 2018 (SCI-Expanded)

# Articles Published in Other Journals

I. Electronic characteristics of asymmetric triple GaAlAs/GaAs and GaInAs/GaAs quantum wells depending on Al and In concentration

ÖZTÜRK O., ÖZTÜRK E., ELAGOZ S.

Cumhuriyet Science Journal, vol.41, no.3, pp.565-570, 2020 (Peer-Reviewed Journal)

II. Electronic properties of double GaAlAs/GaAs and GaInAs/GaAs quantumwells as dependent on well width

ÖZTÜRK O., ÖZTÜRK E., ELAGOZ S.

Cumhuriyet Science Journal, vol.40, no.2, pp.465-470, 2019 (Peer-Reviewed Journal)

# Refereed Congress / Symposium Publications in Proceedings

I. Dependence on Well Widths of the Electronic Features of Triple GaAlAs/GaAs and GaInAs/GaAs Quantum Wells

Öztürk O., Öztürk E., Elagoz S.

5th International Conference on Materials Science and Advanced-Nanotechnologies For Next Generation (MSNG-2018), Nevşehir, Turkey, 4 - 06 October 2018

II. Electronic characteristics of triple GaAlAs/GaAs and GaInAs/GaAs quantum wells depending on Al and In concentration

Öztürk O., Öztürk E., Elagöz S.

5th International Conference on Materials Science and Advanced-Nanotechnologies For Next Generation (MSNG-2018), Nevşehir, Turkey, 4 - 06 October 2018, pp.308

III. Second-Harmonic Generation Susceptibility in Asymmetric Triple Delta-Doped GaAs Structures Öztürk E., Öztürk O., Elagöz S.

5th International Conference on Materials Science and Advanced-Nanotechnologies For Next Generation (MSNG-2018) , Nevşehir, Turkey, 4 - 06 October 2018, pp.309

IV. Depending on Al and In concentration of the electronic properties of asymmetric double GaAlAs/GaAs and GaInAs/GaAs quantum wells

Öztürk O., Öztürk E., Elagöz S.

4th International Conference on Engineering and Natural Sciences (ICENS-2018), Kyyiv, Ukraine, 2 - 06 May 2018, pp.630-635

V. The Effect of Barrier Width on the Electronic Properties of Double GaAlAs / GaAs and GaInAs / GaAs Quantum Wells

Öztürk O., Öztürk E., Elagoz S.

MSNG 2017, Sarajevo, Bosnia And Herzegovina, 28 - 30 June 2017, pp.43

#### **Metrics**

Publication: 19
Citation (WoS): 28
Citation (Scopus): 46
H-Index (WoS): 3
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